Diode Semiconductor Device - Page 1 of 1



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	osure Material:
Glas	
	rall Length:
	0 inches
	ninal Length:
	5 inches
	rall Diameter:
0.37	5 inches
Fun	ction For Which Designed:
Zen	er diode
Μου	Inting Method:
Terr	ninal
Feat	tures Provided:
Herr	netically sealed case
Sem	niconductor Material:
Silic	on
Volt	age Rating In Volts Per Characteristic:
12.4	regulator voltage
Volt	age Tolerance In Percent:
-5.0/	/+5.0
Cur	rent Rating Per Characteristic:
7.50	milliamperes all primaries horsepower metric
Pow	ver Rating Per Characteristic:
400.	0 milliwatts small-signal input power, common-collector absolute
Мах	imum Operating Tempurature Per Measurement Point:
150.	0 degrees celsius case
Terr	ninal Type And Quantity:
2 un	insulated wire lead
Spe	cification Data:
801:	31-release 3092 professional/industrial association specification
She	If Life:
N/a	
Unit	Of Measure:
Dem	nilitarization:
No	
Fiig	
5	0a0